

Numerical computation of one-photon mazer resonances for arbitrary field modes

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We present a novel approach for solving numerically one-dimensional scattering problems and apply it for computing the emission probability of an ultracold atom interacting with an arbitrary field mode of a high- Q cavity. Our method is efficient, stable and succeeds when other numerical integration methods fail. It also replaces and improves advantageously the WKB approximation. The cases of sinusoidal, sech^2 and Gaussian field modes are studied and compared. Divergences with previous works, where WKB was used, are found.

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I. INTRODUCTION

Some recent works have been devoted to the interaction of ultracold atoms with microwave cavities [1–6]. These studies treated the interaction between an incident atom in an excited state and a cavity field containing n photons, taking the quantum mechanical CM motion of the atom into account. This interaction leads to a new kind of induced emission intimately associated with the quantization of the CM motion, named the mazer action [1].

After interaction with the cavity, the atom can be found transmitted in the excited state or in the lower state, or reflected as well. It has been shown [1] that these event probability amplitudes (denoted respectively $T_{a,n}$, $T_{b,n+1}$, $R_{a,n}$ and $R_{b,n+1}$) are given by

$$\begin{aligned} T_{a,n} &= \frac{1}{2}(t_{+n} + t_{-n}) & T_{b,n+1} &= \frac{1}{2}(t_{+n} - t_{-n}) \\ R_{a,n} &= \frac{1}{2}(r_{+n} + r_{-n}) & R_{b,n+1} &= \frac{1}{2}(r_{+n} - r_{-n}) \end{aligned} \quad (1)$$

where $t_{\pm n}$ and $r_{\pm n}$ are, respectively, the transmission and reflection amplitudes of the elementary scattering process of the atom incident upon the potential

$$V_n^\pm(x) = \pm \hbar g \sqrt{n+1} u(x) \quad (2)$$

where x is the atom traveling direction, g is the atom – field coupling strength and $u(x)$ is the cavity field mode function.

The induced emission probability of the atom interacting with the cavity field is then given by

$$P_{em} = |T_{b,n+1}|^2 + |R_{b,n+1}|^2 \quad (3)$$

All these probabilities are strongly dependent on the cavity mode profile. Their calculation needs to solve the one-dimensional time-independent Schrödinger equation. Löffler *et al.* [3] have calculated them as a function of the interaction length $\kappa_n L$ (L is the cavity length and $\kappa_n = \kappa \sqrt{n+1}$ with $\kappa = \sqrt{2mg/\hbar}$, and m the atomic

mass) for various cavity mode functions: mesa, sech^2 and sinusoidal modes. For the two first modes, analytical results of the probability $P_{em}(\kappa_n L)$ have been given. For the sinusoidal modes, detailed Wentzel-Kramers-Brillouin solutions have been presented. Nevertheless, Retamal *et al.* [5] have shown that the WKB approximation may lead to inaccurate predictions for actual interaction and cavity parameters.

The consideration of actual interaction and cavity parameters is a difficult numerical task as they can correspond to very large values of $\kappa_n L$. When no analytical solutions of the Schrödinger equation are available, usual numerical integration methods do not converge rapidly or do not converge at all.

In this paper, we present a novel approach for solving the one-dimensional time-independent Schrödinger equation. Our method is described in Sec. II. It may be applied for any potential function. It is efficient, stable and succeeds when other numerical integration methods fail. It may replace and improve advantageously the WKB approach. Details of the implementation of our method and validity tests are presented in Sec. III.

We apply our method for calculating some new $P_{em}(\kappa_n L)$ curves. In particular, the Gaussian potential has been considered, thinking in open cavities in the microwave or optical field regime. These results are presented in Sec. IV.

II. DESCRIPTION OF THE METHOD

The one-dimensional time-independent Schrödinger equation can be written in atomic units in the form

$$\left(\frac{1}{2} \frac{d^2}{dx^2} + (E - V(x)) \right) \phi(x) = 0 \quad (4)$$

We assume here that the potential $V(x)$ has non zero values only in a given region of the x axis, say

$[x_a, x_b]$. This region is divided into J grid points, denoted $x_1, \dots, x_J$ such that $x_a = x_1 < x_2 < \dots < x_{J-1} < x_J = x_b$. Let us note I_j ($0 < j < J$) the region $[x_j, x_{j+1}]$, $I_0]-\infty, x_1]$, and $I_J [x_J, +\infty[$.

The potential $V(x)$ is approximated in each region I_j by a straight line connecting $V(x_j)$ and $V(x_{j+1})$. The approximated potential is noted $V_{approx}(x)$. Then Schrödinger equation takes the simple form in I_j ($0 \leq j \leq J$):

$$\left(\frac{d^2}{dx^2} + (a_j + b_j x) \right) \phi_j(x) = 0 \quad (5)$$

with $a_0 = a_J = 2E$, $b_0 = b_J = 0$, and for $0 < j < J$

$$\begin{cases} a_j = 2 \left(E - \frac{x_{j+1}V_j - x_jV_{j+1}}{x_{j+1} - x_j} \right) \\ b_j = -2 \frac{V_{j+1} - V_j}{x_{j+1} - x_j} \quad \text{with} \quad V_i = V(x_i), i = j, j+1 \end{cases} \quad (6)$$

The most general solutions of Eq. (5) are given by

$$\phi_j(x) = C_j f_j^+(x) + D_j f_j^-(x) \quad (7)$$

where C_j and D_j are two complex constants and $f_j^+(x)$ and $f_j^-(x)$ 2 functions depending on the a_j and b_j values. These functions are given in Table I.

As shown in Table I, the functions $f_j^+(x)$ and $f_j^-(x)$ depend on the sign of $a_j + b_j x$. To avoid a change of this sign in a given region I_j , the set $x_1, \dots, x_J$ must contain the roots of the equation $V(x) = E$. Thus, the condition $a_j + b_j x > 0$ (resp. $a_j + b_j x < 0$) is equivalent to that $E > V(x)$ (resp. $E < V(x)$) for $x \in I_j$.

The complex constants C_j and D_j in Eq. (7) are determined by use of the wavefunction asymptotic behaviour knowledge ((C_0, D_0) or (C_J, D_J) are supposed to be known) and of the set of conditions imposing the continuity of the wavefunction and its derivative along the x axis :

$$\begin{cases} \phi_j(x_j) = \phi_{j-1}(x_j) \\ \phi'_j(x_j) = \phi'_{j-1}(x_j) \end{cases} \quad (0 < j \leq J). \quad (8)$$

If (C_0, D_0) are given, Eq. (8) may be written as

$$\begin{pmatrix} C_j \\ D_j \end{pmatrix} = A_j(x_j) \begin{pmatrix} C_{j-1} \\ D_{j-1} \end{pmatrix} \quad \text{for } 0 < j \leq J, \quad (9)$$

with

$$A_j = \frac{1}{f_j^+ g_j^- - f_j^- g_j^+} \times \begin{pmatrix} f_{j-1}^+ g_j^- - f_{j-1}^- g_j^+ & f_{j-1}^- g_j^- - f_{j-1}^+ g_{j-1}^- \\ f_j^+ g_{j-1}^+ - f_j^+ g_{j-1}^- & f_j^+ g_{j-1}^- - f_{j-1}^+ g_j^+ \end{pmatrix} \quad (10)$$

and

$$g_i^\pm(x) = \frac{df_i^\pm}{dx}, \quad i = j, j-1. \quad (11)$$

If (C_J, D_J) are known, Eq. (8) should be written

$$\begin{pmatrix} C_{j-1} \\ D_{j-1} \end{pmatrix} = B_j(x_j) \begin{pmatrix} C_j \\ D_j \end{pmatrix} \quad \text{for } J \geq j > 0, \quad (12)$$

with

$$B_j = \frac{1}{f_{j-1}^+ g_{j-1}^- - f_{j-1}^- g_{j-1}^+} \times \begin{pmatrix} f_j^+ g_{j-1}^- - f_{j-1}^- g_j^+ & f_j^- g_{j-1}^- - f_{j-1}^+ g_j^- \\ f_{j-1}^+ g_j^+ - f_j^+ g_{j-1}^- & f_{j-1}^+ g_j^- - f_j^- g_{j-1}^+ \end{pmatrix}. \quad (13)$$

The knowledge of $\phi_j(x)$ in each region I_j defines an approximated wavefunction of the Schrödinger equation (4). The grid point number J fixes the accuracy of the method. The higher J is, the more accurate is the approximated potential $V_{approx}(x)$ and the better is the approximated wavefunction. The actual number J to be considered for a given accuracy depends on various parameters (potential form, energy E , size of the region $[x_a, x_b]$). We show in Sec. III and IV that a few hundreds are typical numbers.

The wavefunctions yielded by our method are not divergent at the classical turning points (where $E = V(x)$), on the contrary of the WKB method. Although some Bessel functions of Table I are divergent at these points (as $z_j(x) \equiv a_j + b_j x = 0$), all the functions $f_j^\pm(x)$ and their derivative $g_j^\pm(x)$ admit finite limits there (see Table II).

The transmission and reflection complex amplitudes (denoted respectively t and r) of a particle incident upon a potential $V(x)$ may be calculated as well (and consequently the induced emission probability (3)). If we consider the outgoing wavefunction $\phi_J(x) = e^{ikx}$ with $k = \sqrt{2E}$, we can calculate the corresponding incoming wavefunction $\phi_0(x) = C_0 \cos(kx) + D_0 \sin(kx)$ by use of relations (12). We then have

$$t = \frac{2}{C_0 - iD_0}, \quad r = \frac{C_0 + iD_0}{C_0 - iD_0} \quad (14)$$

III. METHOD IMPLEMENTATION

We have implemented the method described above on a PC Pentium based computer. Bessel functions of Table I have been coded using algorithms given by Zhang and Jin [7]. The evaluation of the Mathematica[®] Bessel functions has been discarded due to poor performances (thousand times slower than direct computation). For usual cavity parameters, C_0 and D_0 coefficients of Eq. (14) can rapidly become very large. To avoid computation overflow errors, we have adopted a custom number representation. Our internal range of values was $9.9 E \pm (\sim 9 E 18)$ with 15 significants.

As a first test of our method, we checked its ability to converge when the grid point number J increases. We have calculated the induced emission probability P_{em} of an atom interacting with a sech^2 mode profile cavity

($u(x) = \text{sech}^2(x/L)$) as a function of the number J and for a fixed interaction length $\kappa_n L$. Fig. 1 presents the curve obtained in the case of $k/\kappa_n = 0.01$ and $\kappa_n L = 10$. This curve shows very clearly that P_{em} converges to a given value as J increases. Also, in that case, a J number of 200 is sufficient for predictions to the accuracy of the graphics. For this calculation, the region $[x_a, x_b]$ was limited to 16 times the cavity length L (~ 8 times the FWHM of the potential function).

In order to improve the convergence of our method with the number J , we renormalized the approximated potential so that the area under it remained constant whatever value J had. Instead of using $V_i = V(x_i)$ in Eq. (6), we have used $V_i = \alpha V(x_i)$ with α equal to the ratio of the area under $V(x)$ over the area under $V_{approx}(x)$.

The study of the sech^2 mode profile is a good test for a numerical method as there exists an analytical expression for $P_{em}(\kappa_n L)$. In this case we have (see Löffler *et al.* [3])

$$t_n^\pm = \frac{\Gamma[1/2 - i(kL + \xi_n^\pm)] \cdot \Gamma[1/2 - i(kL - \xi_n^\pm)]}{\Gamma[-ikL] \cdot \Gamma[1 - ikL]} \quad (15a)$$

$$r_n^\pm = \frac{\Gamma[ikL] \cdot \Gamma[1 - ikL]}{\Gamma[1/2 + i\xi_n^\pm] \cdot \Gamma[1/2 - i\xi_n^\pm]} t_n^\pm \quad (15b)$$

with $\xi_n^\pm = \sqrt{\pm(\kappa_n L)^2 - 1/4}$.

Fig. 2 shows two $P_{em}(\kappa_n L)$ curves calculated for $k/\kappa_n = 0.01$ and $k/\kappa_n = 0.1$ in the case of the sech^2 mode profile. On this figure, the solid lines represent the analytical results deduced from formulas (1), (3) and (15) while the dotted ones represent those obtained using our method (the grid point number J was fixed to 200). The agreement between these results is very good.

IV. NEW RESULTS

A. Fundamental sinusoidal mode

The fundamental sinusoidal mode profile

$$u(x) = \begin{cases} \sin(\pi x/L) & \text{for } 0 < x < L \\ 0 & \text{elsewhere} \end{cases} \quad (16)$$

has been studied by Löffler *et al.* [3] and Retamal *et al.* [5]. Their conclusions are not in agreement with regard to the behaviour of the induced emission probability for ultracold atoms ($k/\kappa_n = 0.01$) interacting with large cavities ($\kappa_n L$ of the order of 10^5). Such cavity parameters are of a great interest as they correspond to realistic values for Rydberg atoms interacting with microwave cavities in recent experiments performed by the Ecole Normale Supérieure Group [8] (see discussion about the orders of magnitude in [5]). Retamal *et al.* [5] have predicted well resolved resonances in the curve $P_{em}(\kappa_n L)$ for the parameters cited above, whereas the curve predicted

on the basis of the results of Löffler *et al.* [3] looks very different.

We have calculated the $P_{em}(\kappa_n L)$ curve for an atom interacting with this mode profile by use of our method. Fig. 3 presents this curve for $\kappa_n L$ comprised between 100000 and 100010 ($k/\kappa_n = 0.01$ and $J = 100$). Our curve shows the same well resolved resonances as those predicted by Retamal *et al.* [5]. So we confirm their predictions that the WKB approximation cannot be used when considering ultracold atoms with $k/\kappa_n = 0.01$ and realistic interaction lengths of the order of 10^5 . Our calculations confirm also that these resonances have got smeared at $\kappa_n L = 10^5$ if we consider warmer atoms characterized by $k/\kappa_n = 0.1$. For this last value of k/κ_n the WKB approximation still holds and P_{em} is then invariably equal to $1/2$. It is good to remark here the importance of still having resolved resonances in P_{em} for actual interaction and cavity parameters, as this result will permit the possibility of testing, in principle, the mazer effect with present cavities. The construction of a re-entrant cavity, as it was proposed in Ref. [3], would not be necessary for testing the mazer effect, but for improving the resolution of the resonances by approximating a mesa function mode profile.

B. First excited sinusoidal mode

The first excited sinusoidal mode profile

$$u(x) = \begin{cases} \sin(2\pi x/L) & \text{for } 0 < x < L \\ 0 & \text{elsewhere} \end{cases} \quad (17)$$

has been studied by Löffler *et al.* [3]. These authors have derived an expression for P_{em} on the basis of a detailed WKB calculation. They have shown that, for large interaction lengths (without being very explicit about the word “large”), the behaviour of the induced emission probability is described by $P_{em}(\kappa_n L) = \sin^2(\Delta_n)$ with

$$\Delta_n = \kappa_n L \cdot \frac{1}{\pi} \int_0^{\pi/2} \sqrt{(k/\kappa_n)^2 + \cos(x)} dx \quad (18)$$

which can be written $\Delta_n = \kappa_n L \cdot \text{Const.}$ if k/κ_n is a fixed ratio.

In Fig. 4, we present two curves of $P_{em}(\kappa_n L)$ calculated for $\kappa_n L$ comprised between 100000 and 100020 (for $k/\kappa_n = 0.01$ and $k/\kappa_n = 0.1$). The first curve does not exhibit a square sine dependence over the interaction length, whereas the second one does. This indicates that $\kappa_n L = 10^5$ cannot be considered as “large” in the sense of Löffler *et al.* [3] for $k/\kappa_n = 0.01$. For $k/\kappa_n = 0.1$, $\Delta_n = 2\pi\kappa_n L/T$, with the period T equals to ~ 16.3 (according to Eq. (18)). This period is well reproduced by our calculations (see curve (b) on Fig. 4).

It is a remarkable result of Löffler *et al.* [3] the possibility of building state-changing and state-preserving mirrors for atoms by modifying the length of the cavity using

this first excited sinusoidal mode. From Fig. 4 we conclude that resonances in P_{em} for the first excited mode are even narrower than those predicted by a square sine function $\sin^2(\Delta_n)$. This is a very convenient result as we are considering actual interaction and cavity parameters.

C. Gaussian mode

Up to-date, the Gaussian cavity mode profile has not been studied exactly in the quantum theory of the mazer. Löffler *et al.* [3] have argued that the sech^2 mode profile could be used as a good approximation of the Gaussian one.

To verify this assumption, we have calculated various $P_{em}(\kappa_n L)$ curves for the profile

$$u(x) = e^{-\frac{x^2}{2\sigma^2}} \quad (19)$$

The parameter σ was fixed to $\sqrt{2/\pi}L$ in order to adopt the same normalization factor for the two profiles (identical area under the modes).

Fig. 5 shows our results for $k/\kappa_n = 0.1$ in the range $\kappa_n L = 0$ to $\kappa_n L = 20$. Qualitatively both profiles exhibit the same behaviour: the resonances in the curves get smeared with increasing values of $\kappa_n L$. But this phenomenon is not so marked in the case of the Gaussian profile. Resonances still exist for longer interaction lengths. This is not a surprising result as the Gaussian profile is growing more abruptly than the sech^2 one. Thus it is in some sense “closer” to the mesa mode, which exhibits resonances at infinity.

We have also considered the case $k/\kappa_n = 0.01$. Our calculations have shown that 90% damped oscillations are still present in the $P_{em}(\kappa_n L)$ curve for interaction lengths approximately 3 times larger in comparison with the sech^2 mode case. For these calculations, the region $[x_a, x_b]$ was limited to 16 times the cavity length L and the grid point number J was fixed to 300.

As it was pointed out in Ref. [3] the mazer effect is not restricted to the microwave domain and it might be tested more efficiently in the optical domain. Note that typical optical cavities have a Gaussian mode profile and it is possible to consider large coupling constants, fact that will help for testing the mazer effect. We want to call attention to the fact that Hood *et al.*, in Ref. [9], presented the first experimental result for which the interaction energy $\hbar g$ is greater than the atomic kinetic energy ($k/\kappa_n \ll 1$).

V. SUMMARY

We have developed a new method for solving one-dimensional scattering problems that may be applied advantageously instead of the WKB approach. This has enabled us to calculate efficiently the induced emission

probability P_{em} of an atom interacting with a high- Q cavity for various mode profiles. Two sinusoidal modes have been considered. For these cases, we have been able to assert that the WKB approximation cannot be used in the computation of P_{em} for ultracold atoms ($k/\kappa_n = 0.01$) interacting with actual cavities characterized by $\kappa_n L$ of the order of 10^5 . Significant and convenient different physical predictions are found, if we compare our results with previous works [3].

The Gaussian mode profile has also been considered and we have shown that, although it exhibits a similar behaviour in comparison with the sech^2 mode profile, the resonances in the $P_{em}(\kappa_n L)$ curves exist for significantly larger values of $\kappa_n L$. The Gaussian mode is relevant when considering open cavities in the microwave or optical domains.

The presented numerical method will be helpful for computing the induced emission probability in the case of the recently studied two-photon mazer [6], when considering field mode profiles different from the mesa function. This and other applications of this numerical method will be presented elsewhere.

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TABLE I. $f_j^+(x)$ and $f_j^-(x)$ functions defining the general solutions (7). In this table, $J_{1/3}(x)$ and $Y_{1/3}(x)$ denote respectively the first and second kind Bessel functions of order 1/3, $I_{1/3}(x)$ and $K_{1/3}(x)$ the first and second kind modified Bessel functions of order 1/3, $k_j = \sqrt{2(E - V_j)}$, $\rho_j = \sqrt{2(V_j - E)}$, and $z_j(x) = a_j + b_j x$.

$b_j = 0$	$a_j = 0$	$f_j^+(x) = 1$
		$f_j^-(x) = x$
	$a_j > 0$	$f_j^+(x) = \cos(k_j x)$
		$f_j^-(x) = \sin(k_j x)$
	$a_j < 0$	$f_j^+(x) = e^{-\rho_j x}$
		$f_j^-(x) = e^{\rho_j x}$
$b_j \neq 0$	$z_j(x) > 0$	$f_j^+(x) = \sqrt{ z_j(x) } J_{\frac{1}{3}}\left(\frac{2}{3 b_j } z_j(x) ^{\frac{3}{2}}\right)$
		$f_j^-(x) = \sqrt{ z_j(x) } Y_{\frac{1}{3}}\left(\frac{2}{3 b_j } z_j(x) ^{\frac{3}{2}}\right)$
	$z_j(x) < 0$	$f_j^+(x) = \sqrt{ z_j(x) } I_{\frac{1}{3}}\left(\frac{2}{3 b_j } z_j(x) ^{\frac{3}{2}}\right)$
		$f_j^-(x) = \sqrt{ z_j(x) } K_{\frac{1}{3}}\left(\frac{2}{3 b_j } z_j(x) ^{\frac{3}{2}}\right)$

TABLE II. Behaviour of the $f_j^\pm(x)$ functions and their derivative $g_j^\pm(x)$ at the classical turning points when $b_j \neq 0$.

$E > V(x)$ region	$E < V(x)$ region
$f^+(x) \rightarrow 0$	$f^+(x) \rightarrow 0$
$f^-(x) \rightarrow -\frac{1}{\pi} 3b_j ^{1/3} \Gamma(1/3)$	$f^-(x) \rightarrow \frac{1}{2} 3b_j ^{1/3} \Gamma(1/3)$
$g^+(x) \rightarrow \frac{b_j}{ 3b_j ^{1/3} \Gamma(4/3)}$	$g^+(x) \rightarrow -\frac{b_j}{ 3b_j ^{1/3} \Gamma(4/3)}$
$g^-(x) \rightarrow \frac{b_j}{\sqrt{3} 3b_j ^{1/3} \Gamma(4/3)}$	$g^-(x) \rightarrow \frac{\pi b_j}{\sqrt{3} 3b_j ^{1/3} \Gamma(4/3)}$

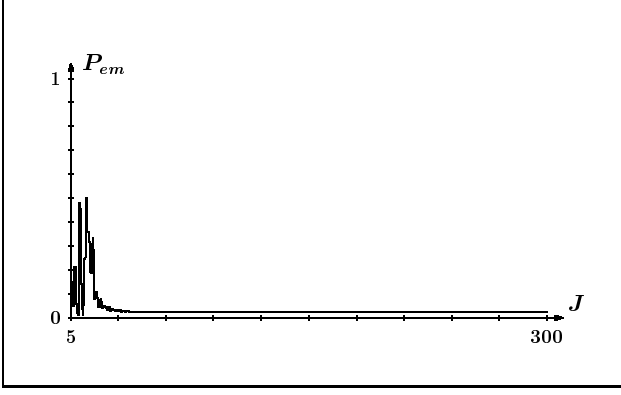


FIG. 1. The induced emission probability P_{em} as a function of the grid point number J for $\kappa_n L = 10$ ($k/\kappa_n = 0.01$, sech^2 cavity mode profile).

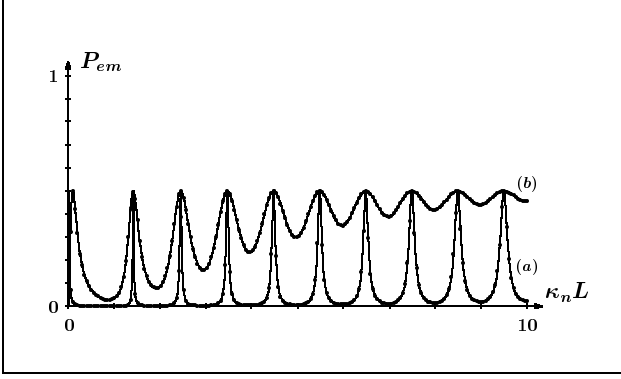


FIG. 2. The induced emission probability P_{em} as a function of the interaction length $\kappa_n L$ for $k/\kappa_n = 0.01$ (a) and $k/\kappa_n = 0.1$ (b). The cavity mode is the sech^2 profile. Solid lines were obtained by analytical calculations, dot ones by our method ($J = 200$).

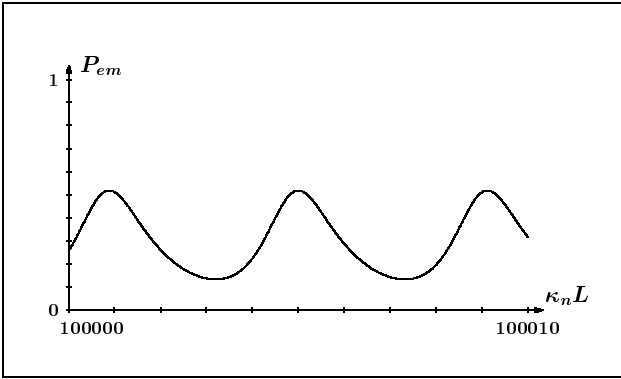


FIG. 3. The induced emission probability P_{em} as a function of the interaction length $\kappa_n L$ for $k/\kappa_n = 0.01$ ($J = 100$, fundamental sinusoidal cavity mode profile).

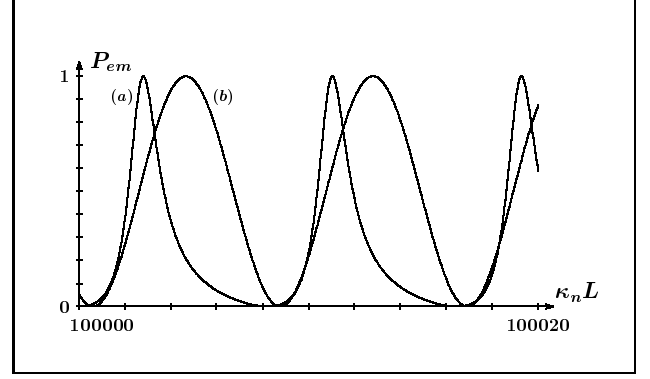


FIG. 4. The induced emission probability P_{em} as a function of the interaction length $\kappa_n L$ for $k/\kappa_n = 0.01$ (a) and $k/\kappa_n = 0.1$ (b) ($J = 200$, first excited sinusoidal cavity mode profile).

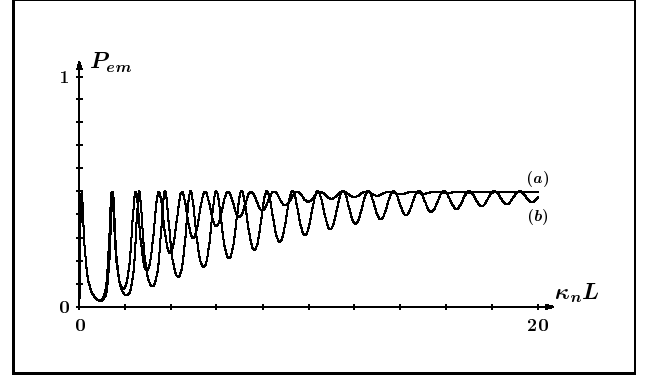


FIG. 5. The induced emission probability P_{em} as a function of the interaction length $\kappa_n L$ for the sech^2 mode profile (a) and the Gaussian profile (b) ($k/\kappa_n = 0.1$, $J = 300$).